

BCR5PM-14LJ

700V - 5A - Triac
Medium Power Use

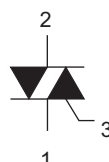
R07DS0950EJ0100
Rev.1.00
Nov 19, 2012

Features

- $I_{T(RMS)}$: 5 A
- V_{DRM} : 800 V ($T_j = 125^\circ\text{C}$)
- T_j : 150°C
- I_{FGT} , I_{RGT} , $I_{RGT III}$: 30 mA
- Viso: 2000 V
- Insulated Type
- Planar Passivation Type
- UL Recognized: File No. E223904

Outline

RENESAS Package code: PRSS0003AA-A
(Package name: TO-220F)



1. T_1 Terminal
2. T_2 Terminal
3. Gate Terminal

Applications

Switching mode power supply, Washing machine, small motor controller, copying machine, electric heater control, and other general controlling devices

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	Conditions
		14		
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	800	V	$T_j = 125^\circ\text{C}$
		700		$T_j = 150^\circ\text{C}$
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	840	V	

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T(RMS)}$	5	A	Commercial frequency, sine full wave 360° conduction, $T_c = 113^\circ\text{C}$
Surge on-state current	I_{TSM}	50	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusion	I^2t	10.4	A^2s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	$P_{G(AV)}$	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I_{GM}	2	A	
Junction Temperature	T_j	-40 to $+150$	$^\circ\text{C}$	
Storage temperature	T_{stg}	-40 to $+150$	$^\circ\text{C}$	
Mass	—	2.0	g	Typical value
Isolation voltage ^{Note5}	Viso	2000	V	$T_a = 25^\circ\text{C}$, AC 1 minute, $T_1 \bullet T_2 \bullet G$ terminal to case

Electrical Characteristics

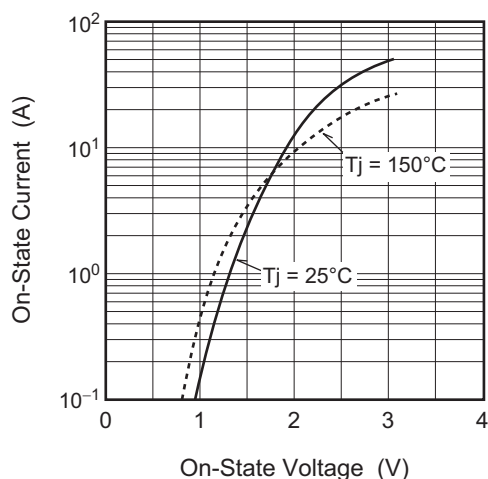
Parameter	Symbol	Rated value			Unit	Test conditions
		Min.	Typ.	Max.		
Repetitive peak off-state current	I_{DRM}	—	—	2.0	mA	$T_j = 150^\circ\text{C}$, V_{DRM} applied
On-state voltage	V_{TM}	—	—	1.8	V	$T_c = 25^\circ\text{C}$, $I_{\text{TM}} = 7\text{ A}$, instantaneous measurement
Gate trigger voltage ^{Note2}	I V_{FGTI}	—	—	1.5	V	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II V_{RGTI}	—	—	1.5	V	
	III V_{RGTIII}	—	—	1.5	V	
Gate trigger current ^{Note2}	I I_{FGTI}	—	—	30	mA	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II I_{RGTI}	—	—	30	mA	
	III I_{RGTIII}	—	—	30	mA	
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{\text{DRM}}$
		0.1	—	—	V	$T_j = 150^\circ\text{C}$, $V_D = 1/2 V_{\text{DRM}}$
Thermal resistance	$R_{\text{th (j-c)}}$	—	—	4.9	$^\circ\text{C/W}$	Junction to case ^{Note3}
Critical-rate of rise of off-state commutation voltage ^{Note4}	$(dv/dt)_c$	5	—	—	V/ μs	$T_j = 125^\circ\text{C}$
		1	—	—	V/ μs	$T_j = 150^\circ\text{C}$

- Notes: 1. Gate open.
2. Measurement using the gate trigger characteristics measurement circuit.
3. The contact thermal resistance $R_{\text{th (c-f)}}$ in case of greasing is 0.5°C/W .
4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
5. Make sure that your finished product containing this device meets your safe isolation requirements.
For safety, it's advisable that heatsink is electrically floating.

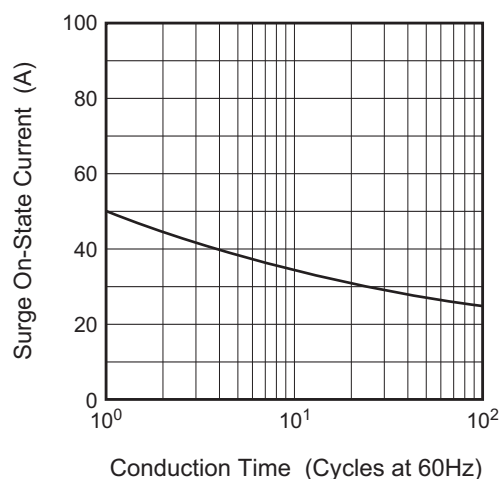
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j = 125/150^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c = -2.5\text{ A/ms}$ 3. Peak off-state voltage $V_D = 400\text{ V}$	

Performance Curves

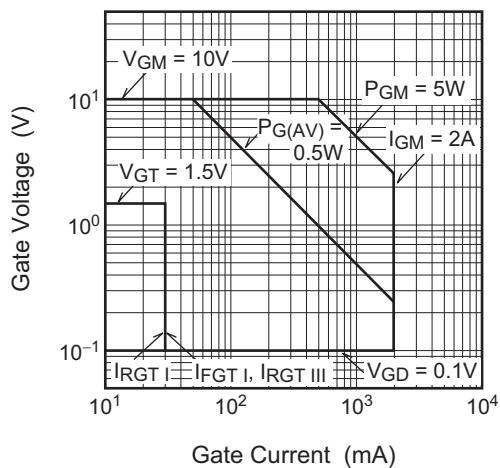
Maximum On-State Characteristics



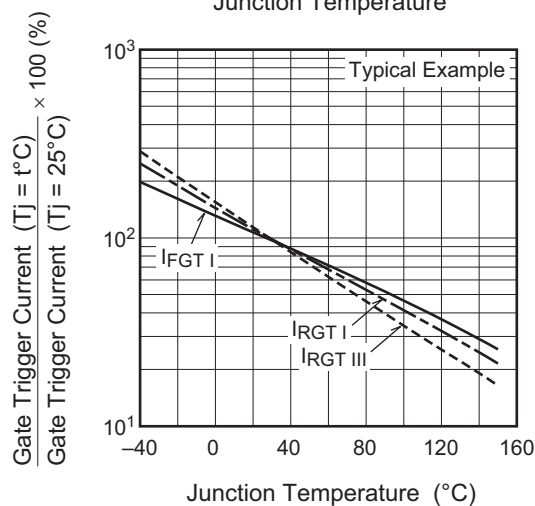
Rated Surge On-State Current



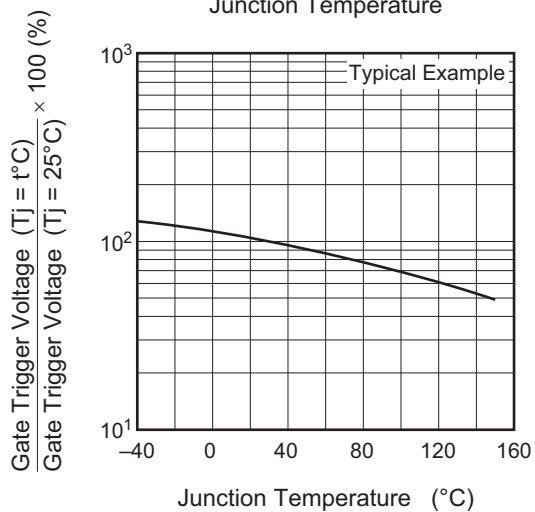
Gate Characteristics (I, II and III)



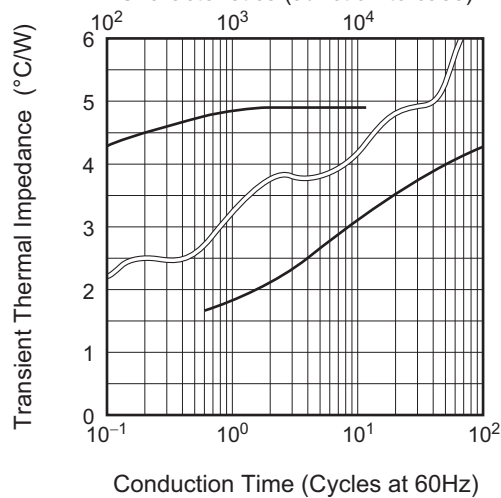
Gate Trigger Current vs. Junction Temperature



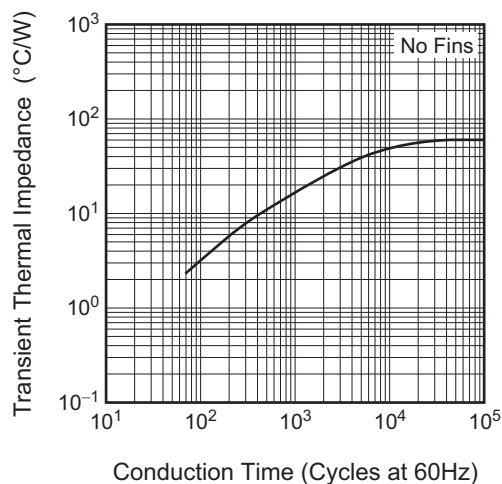
Gate Trigger Voltage vs. Junction Temperature



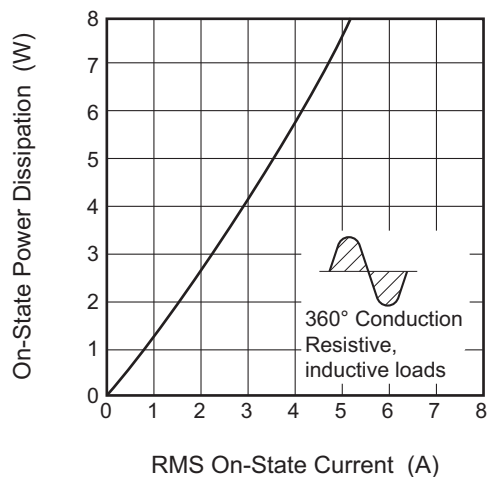
Maximum Transient Thermal Impedance Characteristics (Junction to case)



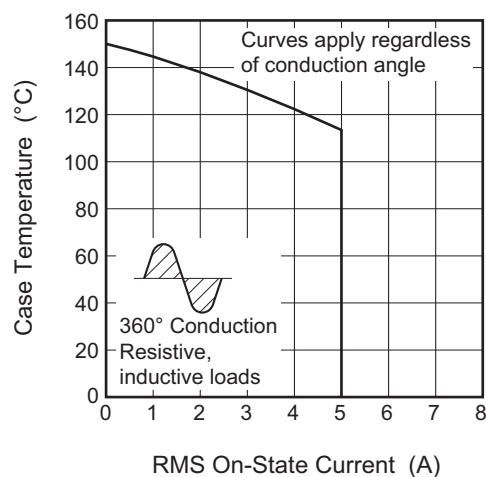
Maximum Transient Thermal Impedance Characteristics (Junction to ambient)



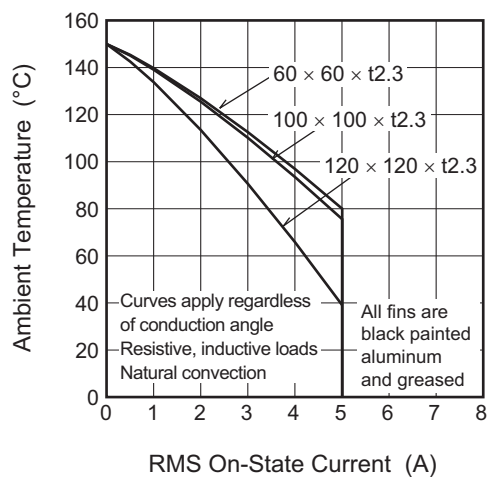
Maximum On-State Power Dissipation



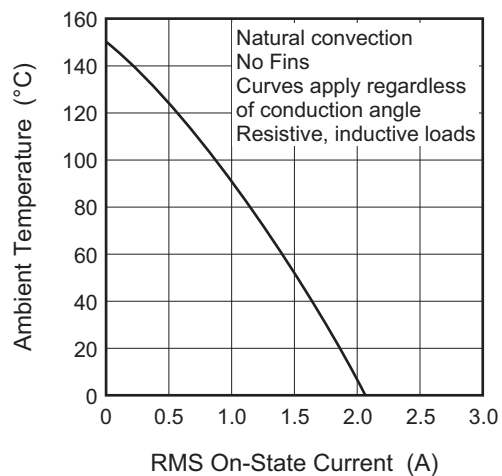
Allowable Case Temperature vs. RMS On-State Current



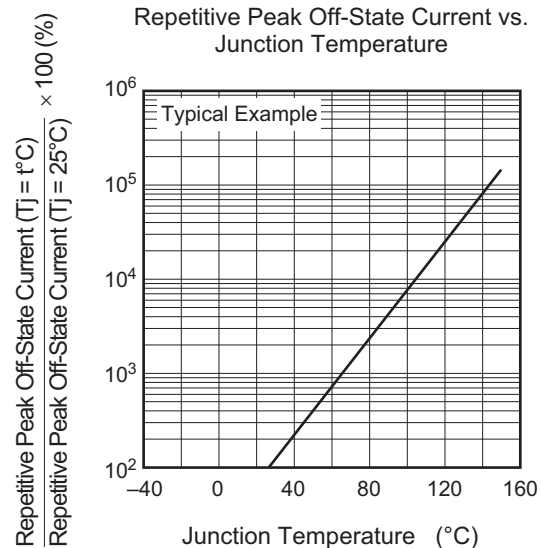
Allowable Ambient Temperature vs. RMS On-State Current

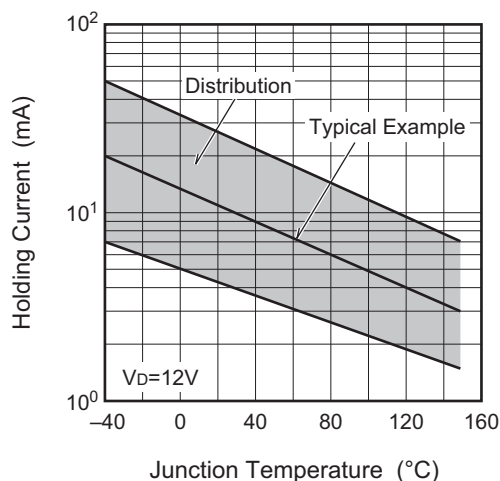
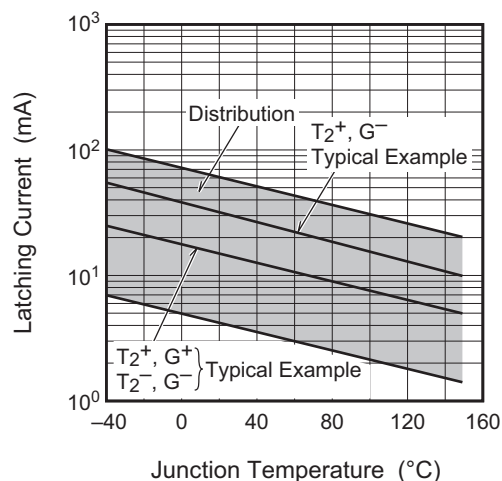
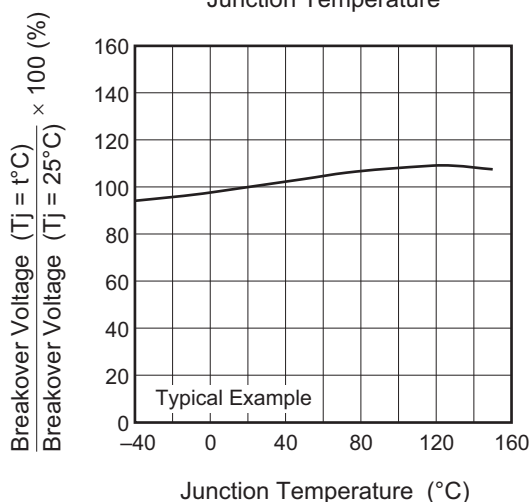
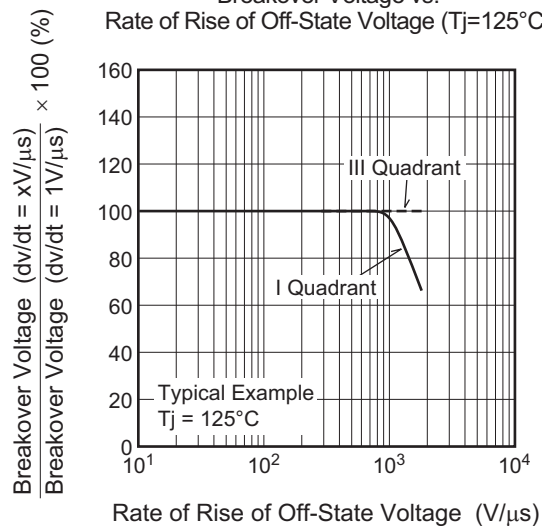
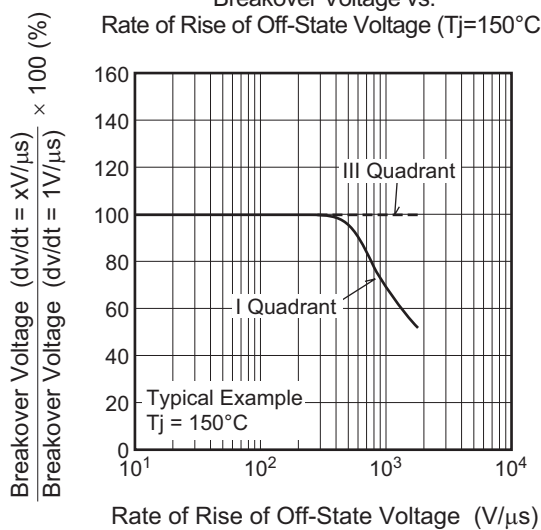
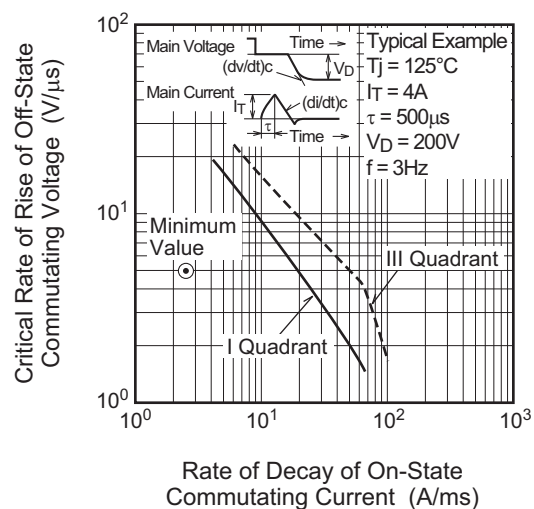


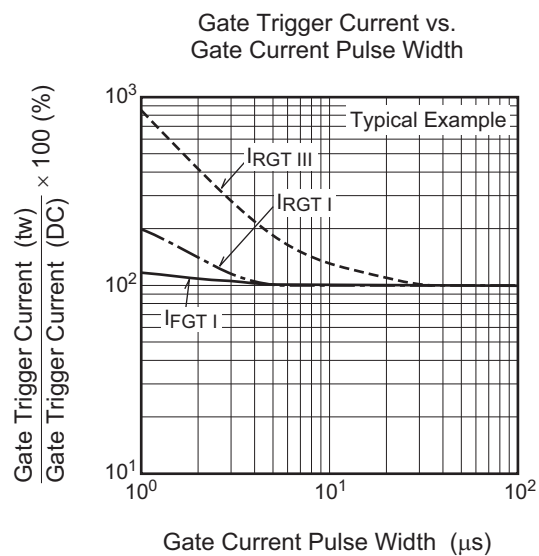
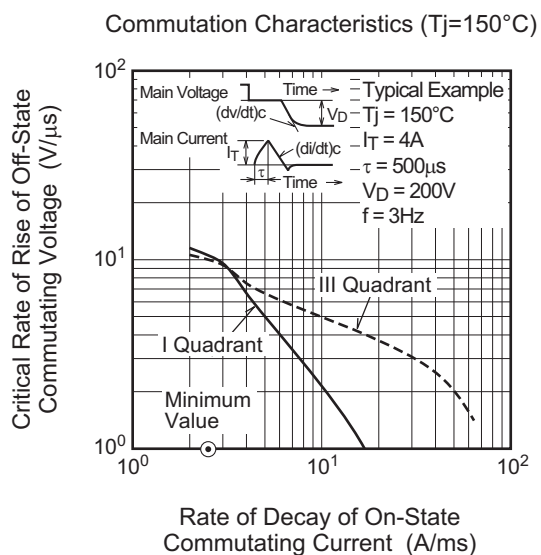
Allowable Ambient Temperature vs. RMS On-State Current



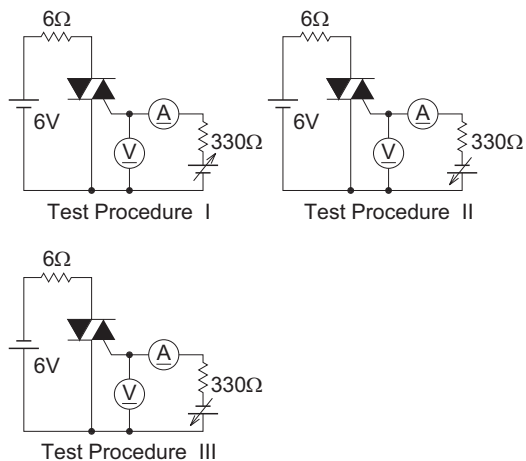
Repetitive Peak Off-State Current vs. Junction Temperature



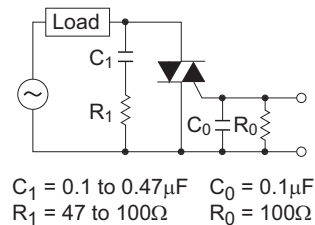
Holding Current vs.
Junction TemperatureLatching Current vs.
Junction TemperatureBreakover Voltage vs.
Junction TemperatureBreakover Voltage vs.
Rate of Rise of Off-State Voltage ($T_j = 125^{\circ}\text{C}$)Breakover Voltage vs.
Rate of Rise of Off-State Voltage ($T_j = 150^{\circ}\text{C}$)Commutation Characteristics ($T_j = 125^{\circ}\text{C}$)



Gate Trigger Characteristics Test Circuits



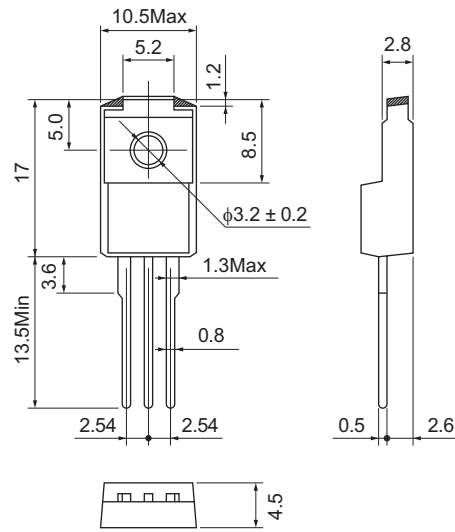
Recommended Circuit Values Around The Triac



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-220F	SC-67	PRSS0003AA-A	T220F	2.0g

Unit: mm



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR5PM-14LJ#B00	Bag	100 pcs.	Straight type
BCR5PM-14LJ-A8#B00	Tube	50 pcs.	A8 Lead form

Note: Please confirm the specification about the shipping in detail.

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